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SEMICONDUCTOR

DM74LS30 8-Input NAND Gate

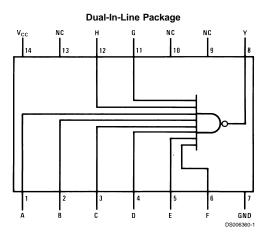
General Description

This device contains a single gate which performs the logic NAND function.

Features

 Alternate Military/Aerospace device (54LS30) is available. Contact a Fairchild Semiconductor Sales Office/Distributor for specifications.

Connection Diagram



Order Number 54LS30DMQB, 54LS30FMQB, 54LS30LMQB, DM54LS30J, DM54LS530W, DM74LS30M or DM74LS30N See Package Number E20A, J14A, M14A, N14A or W14B

Function Table

$Y = \overline{ABCDEFGH}$

Inputs	Output		
A thru H	Y		
All Inputs H	L		
One or More	н		
Input L			
Input L H = High Logic Level			

L = Low Logic Level

DM74LS30 8-Input NAND Gate

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Absolute	Maximum	Ratings (Note 1)
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Supply Voltage
Input Voltage
Operating Free Air Temperature Range

DM54LS and 54LS DM74LS Storage Temperature Range -55°C to +125°C 0°C to +70°C -65°C to +150°C

Recommended Operating Conditions

Symbol	Parameter	DM54LS30		DM74LS30			Units	
		Min	Nom	Max	Min	Nom	Max	
V _{cc}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH}	High Level Input Voltage	2			2			V
V _{IL}	Low Level Input Voltage			0.7			0.8	V
I _{он}	High Level Output Current			-0.4			-0.4	mA
I _{OL}	Low Level Output Current			4			8	mA
T _A	Free Air Operating Temperature	-55		125	0		70	°C

7V

7V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Electrical Characteristics

over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter Conditions			Min	Тур	Max	Units
					(Note 2)		
VI	Input Clamp Voltage	V_{CC} = Min, I _I = -18 mA				-1.5	V
V _{OH}	High Level Output	V _{CC} = Min, I _{OH} = Max	V _{CC} = Min, I _{OH} = Max DM54		3.4		V
	Voltage	V _{IL} = Max	DM74	2.7	3.4		
V _{OL}	Low Level Output	V _{CC} = Min, I _{OL} = Max	DM54		0.25	0.4	v
	Voltage	V _{IH} = Min	DM74		0.35	0.5	
		I_{OL} = 4 mA, V_{CC} = Min	DM74		0.25	0.4	
I _I	Input Current @ Max	$V_{CC} = Max, V_I = 7V$				0.1	mA
	Input Voltage						
I _{IH}	High Level Input Current	V _{CC} = Max, V _I = 2.7V				20	μA
I _{IL}	Low Level Input Current	V_{CC} = Max, V_{I} = 0.4V				-0.4	mA
l _{os}	Short Circuit	V _{CC} = Max	DM54	-20		-100	mA
	Output Current	(Note 3)	DM74	-20		-100	
I _{CCH}	Supply Current with	V _{CC} = Max			0.35	0.5	mA
	Outputs High						
I _{CCL}	Supply Current with	V _{CC} = Max			0.6	1.1	mA
	Outputs Low						

Switching Characteristics

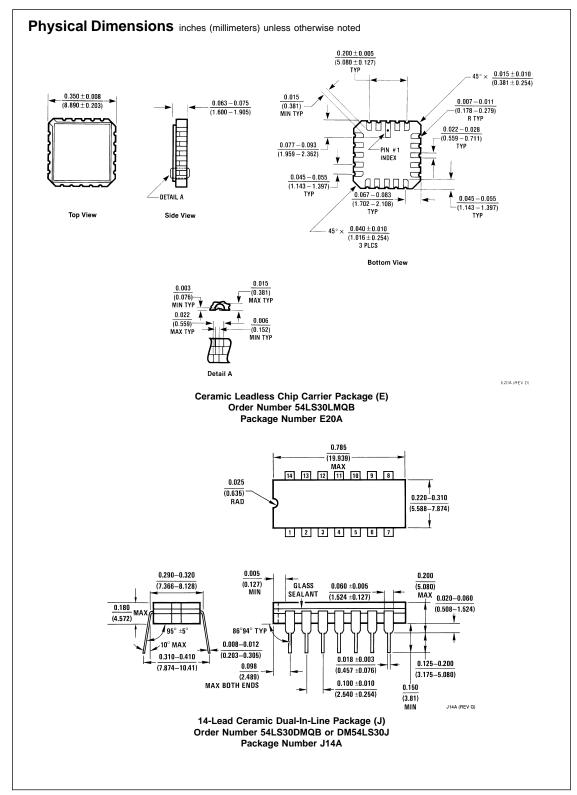
at V_{CC} = 5V and T_A = 25°C (See Section 1 for Test Waveforms and Output Load)

	Parameter					
Symbol		C _L = 15 pF		C _L = 50 pF		Units
		Min	Max	Min	Max	
t _{PLH}	Propagation Delay Time	4	12	5	18	ns
	Low to High Level Output					
t _{PHL}	Propagation Delay Time	4	15	5	20	ns
	High to Low Level Output					

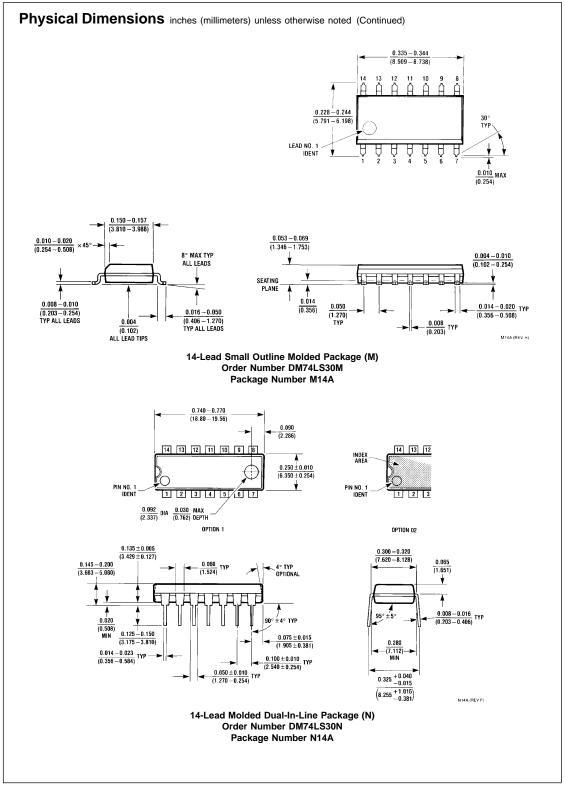
Note 2: All typicals are at V_{CC} = 5V, T_A = 25°C.

Note 3: Not more than one output should be shorted at a time, and the duration should not exceed one second.





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